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## IGBT wafer diameter change in Power Modules

For further information, please contact your regional Vishay office.

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**Description of Change:** Change of wafer diameter of IGBT chips used in below power module.

FROM:8 inches wafer diameter TO: 12 inches wafer diameter

**Classification of Change:** Obsolescence of 8 inches wafer from IGBT supplier.

**Expected Influence on Quality/Reliability/Performance:** There will be no effect on product quality, reliability or performance.

**Part Numbers/Series/Families Affected:** VS-GT300YH120N

**Vishay Brand(S):** Vishay Semiconductors

**Time Schedule:**

Start Shipment Date: Wed May 31, 2023

**Sample Availability:** Samples available upon request

**Product Identification:** Batch code (contact factory for the details)

**Qualification Data:** Available upon request

**This PCN is considered approved, without further notification, unless we receive specific customer concerns before Tue May 30, 2023 or as specified by contract.**

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